

ZXTP2013Z

100V PNP LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > -100V
- I_C = -3.5A High Continuous Current
- R_{SAT} = 57mΩ for a Low Equivalent On-Resistance
- Low Saturation Voltage V_{CE(SAT)} < -85mV @ I_C = -1A
- hFE Specified Up to -10A for High Current Gain Hold Up
- Complementary NPN Type: ZXTN2011Z
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.05 grams (Approximate)

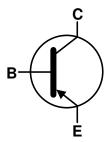
Application

- · Emergency Lighting Circuits
- Motor Driving (Including DC Fans)
- Backlight Inverters
- Power Switches
- Gate Driving MOSFETs and IGBTs

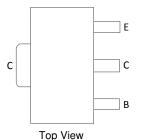




Top View



Device Symbol



Pin Out

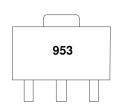
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTP2013ZTA	AEC-Q101	953	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



953 = Product Type Marking Code



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-140	V
Collector-Emitter Voltage	VCEO	-100	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-3.5	Α
Peak Pulse Current	I _{CM}	-10	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	Pn	1.5	W
Linear Derating Factor	PD	12	mW/°C
Power Dissipation (Note 6)	D-	2.1	W
Linear Derating Factor	P _D	16.8	mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	Reja	83	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	60	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

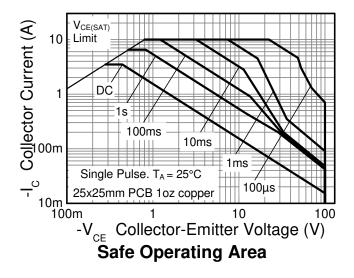
Notes:

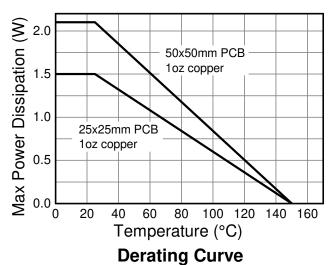
^{5.} For a device surface mounted on 25mm × 25mm × 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.

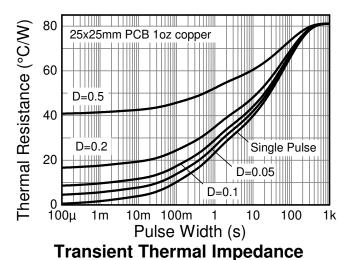
^{6.} Same as note (5), except the device is mounted on 50mm × 50mm single sided 1oz weight copper.

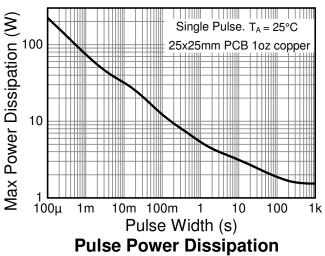


Thermal Characteristics and Derating Information











Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

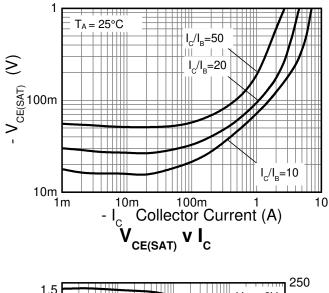
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-140	-160	_	V	$I_C = -100\mu A$
Collector-Emitter Breakdown Voltage (Note 7)	BVcer	-140	-160	_	V	$I_C = -1\mu A$, $R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 7)	BVceo	-100	-115	_	V	Ic = -10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.1	_	V	$I_E = -100\mu A$
Collector Cutoff Current	Ісво	_	< -1	-20	nA	V _{CB} = -100V
General Garant			_	-500	nA	$V_{CB} = -100V, T_A = +100^{\circ}C$
Collector Cutoff Current	ICER	_	< -1	-20	nA	V _{CB} = -100V
	R≤1kΩ			-500	nA	$V_{CB} = -100V, T_A = +100^{\circ}C$
Emitter Cutoff Current	I _{EBO}		< -1	-10	nA	V _{EB} = -6V
DC Current Transfer Static Ratio (Note 7)	hFE	100 100 25 15	250 200 50 30 5	300 — — —	_	IC = -10mA, VCE = -1V IC = -1A, VCE = -1V IC = -3A, VCE = -1V IC = -4A, VCE = -1V IC = -10A, VCE = -1V
Collector-Emitter Saturation Voltage (Note 7)	VCE(SAT)	_	-20 -65 -110 -230	-30 -85 -135 -300	mV	IC = -100mA, IB = -10mA IC = -1A, IB = -100mA IC = -2A, IB = -200mA IC = -4A, IB = -400mA
Base-Emitter Saturation Voltage (Note 7)	$V_{BE(SAT)}$	_	-970	-1060	mV	$I_C = -4A$, $I_B = -400mA$
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(ON)}		-910	-1030	mV	$I_C = -4A$, $V_{CE} = -1V$
Transitional Frequency	fτ	_	125	-	MHz	Ic = -100mA, VcE = -10V, f = 50MHz
Output Capacitance (Note 7)	Сово	_	42		pF	V _{CB} = -10V, f = 1MHz
Switching Time	ton	_	42	_	ns	$V_{CC} = -10V, I_{C} = -1A,$
	toff		540		110	$I_{B1} = -I_{B2} = -100 \text{mA}$

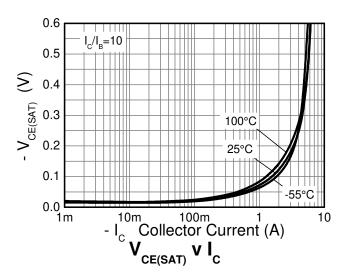
Note:

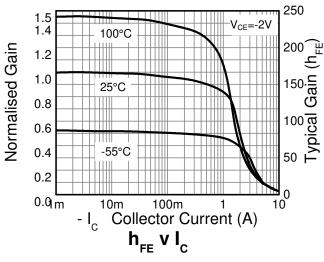
7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

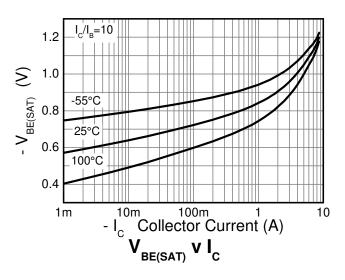


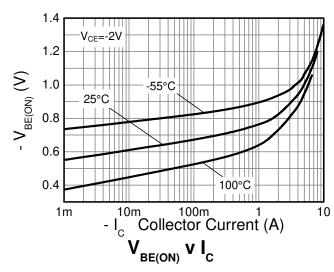
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









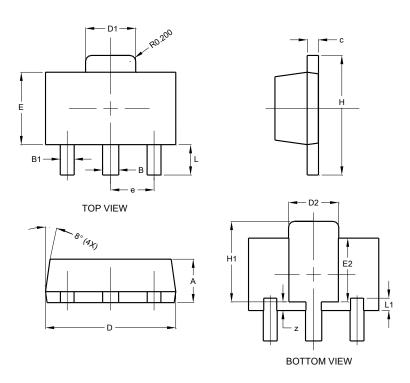




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

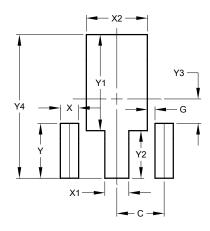


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
٦	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	value
Dillicipions	(in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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